General purpose transistor (isolated transistor and diode)

EML11 / UML11N

2SA1774 and a RB521S-30 are housed independently in a EMT5 or UMT5 package.

Applications

DC / DC converter Motor driver

Features

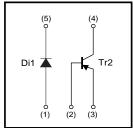
- Tr2: Small Signal Transistor
 Di1: Low V_F
- 2) Small package

●Structure

Silicon epitaxial planar transistor Schottky barrier diode

The following characteristics apply to both Di1 and Tr2.

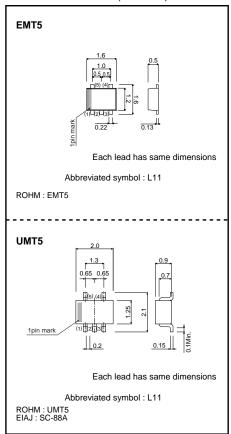
●Equivalent circuit (EML11 / UML11N)



Packaging specifications

Туре	EML11	UML11N
Package	EMT5	UMT5
Marking	L11	L11
Code	T2R	TR
Basic ordering unit(pieces)	8000	3000

●External dimensions (Unit: mm)



●Absolute maximum ratings (Ta=25°C)

Di1

Parameter	Symbol	Limits	Unit
Average rectified forward current	lo	200	mA
Forward current surge peak (60Hz, 1∞)	IFSM	1	Α
Reverse voltage (DC)	VR	30	V
Junction temperature	Tj	125	°C

Tr2

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	-60	V
Collector-emitter voltage	Vceo	-50	V
Emitter-base voltage	Vево	-6	V
Collector current	Ic	-150	mA
Power dissipation	P□	120	mW *
Junction temperature	Tj	150	°C

^{*} Each terminal mounted on a recommended.

Di1 / DTr2

Parameter	Symbol	Limits	Unit
Power dissipation	Pd	150	mW *
Storage temperature	Tstg	-55 to +125	°C

^{*} Each terminal mounted on a recommended.

●Electrical characteristics (Ta=25°C)

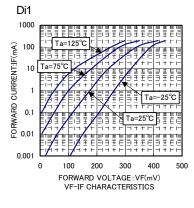
Di1

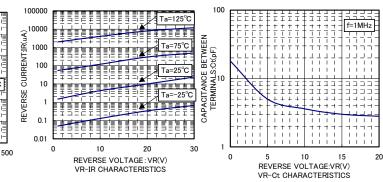
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	_	0.40	0.50	V	I _F =200mA
Reverse current	lr	-	4.0	30	μА	V _R =10V

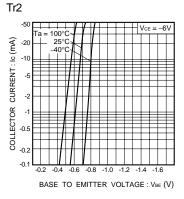
Tr2

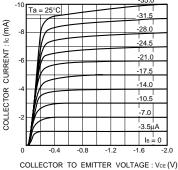
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-60	_	-	V	Ic=-50μA
Collector-emitter breakdown voltage	BVceo	-50	-	-	V	Ic=-1mA
Emitter-base breakdown voltage	ВУево	-6	-	-	V	Iε=-50μA
Collector cutoff current	Ісво	-	-	-100	nA	Vcb=-60V
Emitter cutoff current	ІЕВО	-	-	-100	nA	V _{EB} =-6V
Collector-emitter saturation voltage	VCE(sat)	-	-	-500	mV	Ic/I _B =-50mA/-5mA
DC current transfer ratio	hfe	180	-	390	-	Vce=-6V, Ic=-1mA
Transition frequency	f⊤	-	140	-	MHz	Vce=-12V, Ie=2mA, f=100MHz
Output capacitance	Cob	-	4.0	5.0	pF	Vcb=-12V, Ie=0A, f=1MHz

●Electrical characteristic curves









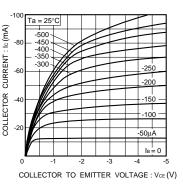
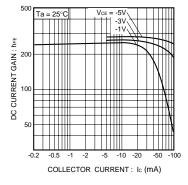
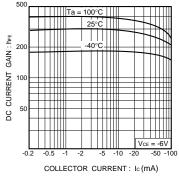


Fig.1 Grounded emitter propagation characteristics

Fig.2 Grounded emitter output characteristics (I)

Fig.3 Grounded emitter output characteristics (II)





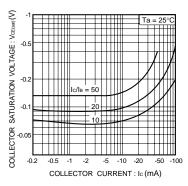


Fig.4 DC current gain vs. collector current (I)

Fig.5 DC current gain vs. collector current (II)

Fig.6 Collector-emitter saturation voltage vs. collector current (I)

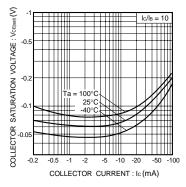


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

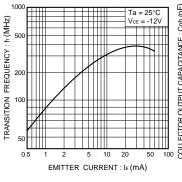


Fig.8 Gain bandwidth product vs. emitter current

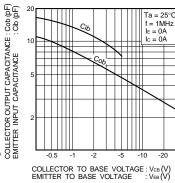


Fig.9 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

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